

Features

- High-speed, low-noise non-inverting 1-7 buffer
- Switching speed up to 128 MHz
- Supports up to three mobile SDRAM DIMMs
- Low skew (<250ps) between any two output clocks
- I²C Serial Configuration interface
- Multiple V_{DD}, V_{SS} pins for noise reduction
- 3.3V power supply voltage
- Packaging (Pb-free & Green available):
- 20-pin QSOP(Q)

Description

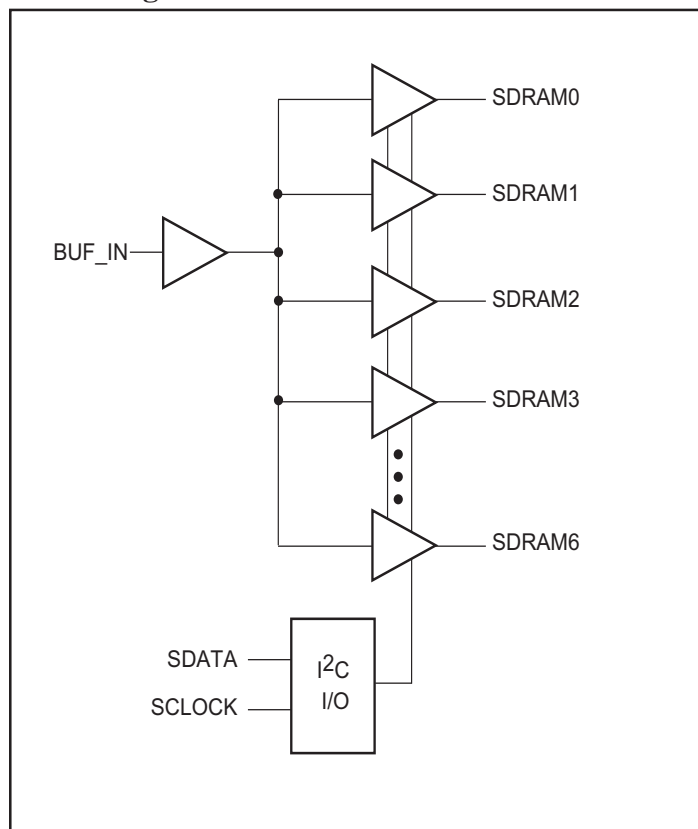
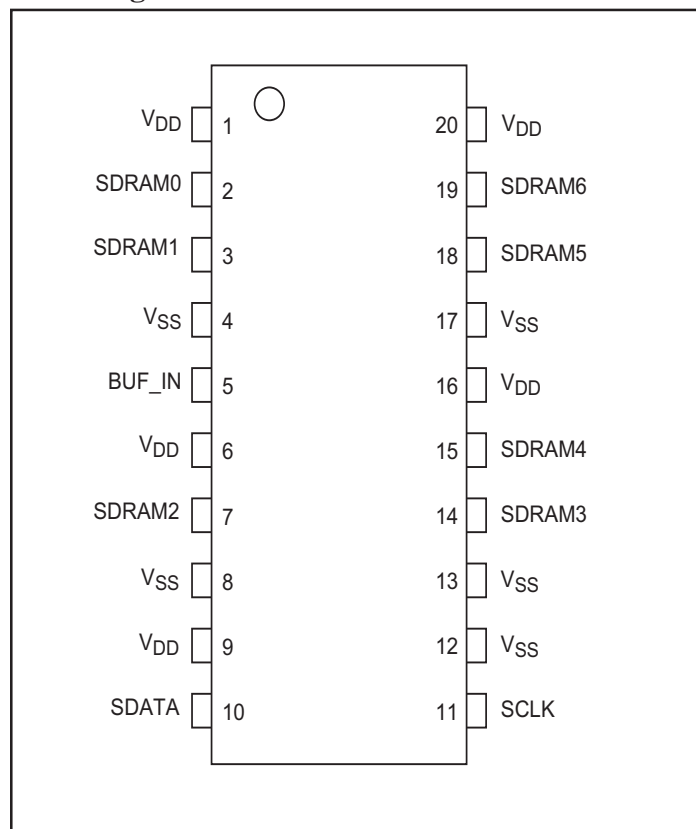
The PI6C185-00 is a high-speed low-noise 1-7 non-inverting buffer designed for SDRAM clock buffer applications.

This buffer is intended to be used with the PI6C10X clock generator for Intel Architecture-based Mobile systems.

At power up all SDRAM output are enabled and active. The I²C Serial control may be used to individually activate/deactivate any of the 7 output drivers.

Note:

Purchase of I²C components from Pericom conveys a license to use them in an I²C system as defined by Philips.

Block Diagram

Pin Configuration


Pin Description

Pin	Signal	Type	Qty.	Description
2,3,7,14,15,18,19	SDRAM[0.6]	I	7	Buffered Clock Outputs
5	BUF_IN	I	1	Clock Buffer Input
10	SDATA	I/O	1	Serial Data for I ² C interface, internal pull-up.
11	SCLK	I	1	Serial Clock for I ² C interface, internal pull-up
1,6,9,16,20	V _{DD}	Power	5	3.3V Power Supply
4,8,12,13,17	V _{SS}	Ground	5	Ground

PI6C185-00 I²C Address Assignment

A6	A5	A4	A3	A2	A1	A0	R/W
1	1	0	1	0	0	1	0

PI6C185 Serial Configuration Map

Byte0: SDRAM Active/Inactive Register
(1 = enable, 0 = disable)

Bit	Pin#	Description
Bit 7	15	SDRAM4 (Active/Inactive)
Bit 6	14	SDRAM3 (Active/Inactive)
Bit 5	-	NC (Initialize to 0)
Bit 4	7	SDRAM2 (Active/Inactive)
Bit 3	-	NC (Initialize to 0)
Bit 2	-	NC (Initialize to 0)
Bit 1	3	SDRAM1 (Active/Inactive)
Bit 0	2	SDRAM0 (Active/Inactive)

Byte1: SDRAM Active/Inactive Register
(1 = enable, 0 = disable)

Bit	Pin#	Description
Bit 7	-	NC (Initialize to 0)
Bit 6	-	NC (Initialize to 0)
Bit 5	-	NC (Initialize to 0)
Bit 4	-	NC (Initialize to 0)
Bit 3	-	NC (Initialize to 0)
Bit 2	-	NC (Initialize to 0)
Bit 1	19	SDRAM6 (Active/Inactive)
Bit 0	18	SDRAM5 (Active/Inactive)

Note:

Inactive means outputs are held LOW and are disabled from switching

2-Wire I²C Control

The I²C interface permits individual enable/disable of each clock output and test mode enable.

The PI6C185-00 is a slave receiver device. It can not be read back. Sub addressing is not supported. To change one of the control bytes, all preceding bytes must be sent.

Every bite put on the SDATA line must be 8-bits long (MSB first), followed by an acknowledge bit generated by the receiving device.

During normal data transfers SDATA changes only when SCLK is LOW. Exceptions: A HIGH to LOW transition on SDATA while SCLK is HIGH indicates a “start” condition. A LOW to HIGH transition on SDATA while SCLK is HIGH is a “stop” condition and indicates the end of a data transfer cycle.

Each data transfer is initiated with a start condition and ended with a stop condition. The first byte after a start condition is always a 7-bit address byte followed by a read/write bit. (HIGH = read from addressed device, LOW = write to addressed device). If the device’s own address is detected, PI6C185-00 generates an acknowledge by pulling SDATA line LOW during ninth clock pulse, then accepts the following data bytes until another start or stop condition is detected.

Following acknowledgement of the address byte (0D2H), two more bytes must be sent:

1. “Command Code” byte, and
2. “Byte Count” byte.

Although the data bits on these two bytes are “don’t care,” they must be sent and acknowledged.

Maximum Ratings

(Above which the useful life may be impaired.
For user guidelines, not tested.)

Storage Temperature -65°C to +150°C
 Ambient Temperature with Power Applied -40°C to +85°C
 3.3V Supply Voltage to Ground Potential -0.5V to +4.6V
 DC Input Voltage -0.5V to +4.6V

Note:

Stresses greater than those listed under MAXIMUM RATINGS may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.

Supply Current (V_{DD}=+3.465V, C_{LOAD}=Max.)

Symbol	Parameter	Test Condition	Min.	Typ.	Max.	Units
I _{DD}	Supply Current	BUF_IN = 0 MHz			3	mA
I _{DD}	Supply Current	BUF_IN = 66.66 MHz		85		
I _{DD}	Supply Current	BUF_IN = 100.0 MHz		130		
I _{DD}	Supply Current	BUF_IN = 133.3 MHz		220		

DC Operating Specifications ($V_{DD} = +3.3V \pm 5\%$, $T_A = 0^\circ C - 70^\circ C$)

Symbol	Parameter	Test Condition	Min.	Max.	Units
Input Voltage					
V_{IH}	Input high voltage	V_{DD}	2.0	$V_{DD} + 0.3$	V
V_{IL}	Input low voltage		$V_{SS} - 0.3$	0.8	
I_{IL}	Input leakage current	$0 < V_{IN} < V_{DD}$	-5	+5	mA
$V_{DD}[0-9] = 3.3V \pm 5\%$					
V_{OH}	Output high voltage	$I_{OH} = -1mA$	2.4		V
V_{OL}	Output low voltage	$I_{OL} = 1mA$		0.4	
C_{OUT}	Output pin capacitance			6	pF
C_{IN}	Input pin capacitance			5	
L_{PIN}	Pin Inductance			7	nH
T_A	Ambient Temperature	No Airflow	0	70	$^\circ C$

SDRAM Clock Buffer Operating Specification

Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Units
I_{OHMIN}	Pull-up current	$V_{OUT} = 2.0V$	-54			mA
I_{OHMAX}	Pull-up current	$V_{OUT} = 3.135V$			-46	
I_{OLMIN}	Pull-down current	$V_{OUT} = 1.0V$	54			
I_{OLMAX}	Pull-down current	$V_{OUT} = 0.4V$			53	
$t_{thSDRAM}$	Output rise edge rate SDRAM only	$3.3V \pm 5\%$ @04V-2.4V	1.5		4	V/ns
$t_{thSDRAM}$	Output fall edge rate SDRAM only	$3.3V \pm 5\%$ @2.4V-0.4V	1.5		4	

AC Timing

Symbol	Parameter	66 MHz		100 MHz		133.3 MHz		Units
		Min.	Max.	Min.	Max.	Min.	Max.	
t_{SDKP}	SDRAM CLK period	15.0	15.5	10.0	10.5	7.5	8.0	ns
t_{SDKH}	SDRAM CLK high time	5.6		3.3		2.2		
t_{SDKL}	SDRAM CLK low time	5.3		3.1		2.0		
t_{SDRISE}	SDRAM CLK rise time	1.5	4.0	1.5	4.0	1.4	4.0	V/ns
t_{SDFALL}	SDRAM CLK fall time	1.5	4.0	1.5	4.0	1.4	4.0	
t_{PLH}	SDRAM Buffer LH prop delay	1.0	5.0	1.0	5.0	1.0	5.0	ns
t_{PHL}	SDRAM Buffer HL prop delay	1.0	5.0	1.0	5.0	1.0	5.0	
t_{PZL}, t_{PZH}	SDRAM Buffer Enable delay	1.0	8.0	1.0	8.0	1.0	8.0	
t_{PLZ}, t_{PHZ}	SDRAM Buffer Disable delay	1.0	8.0	1.0	8.0	1.0	8.0	
Duty Cycle	Measured at 1.5V	45	55	45	55	45	45	%
t_{SDSKW}	SDRAM Output to Output Skew		250		250		250	ps

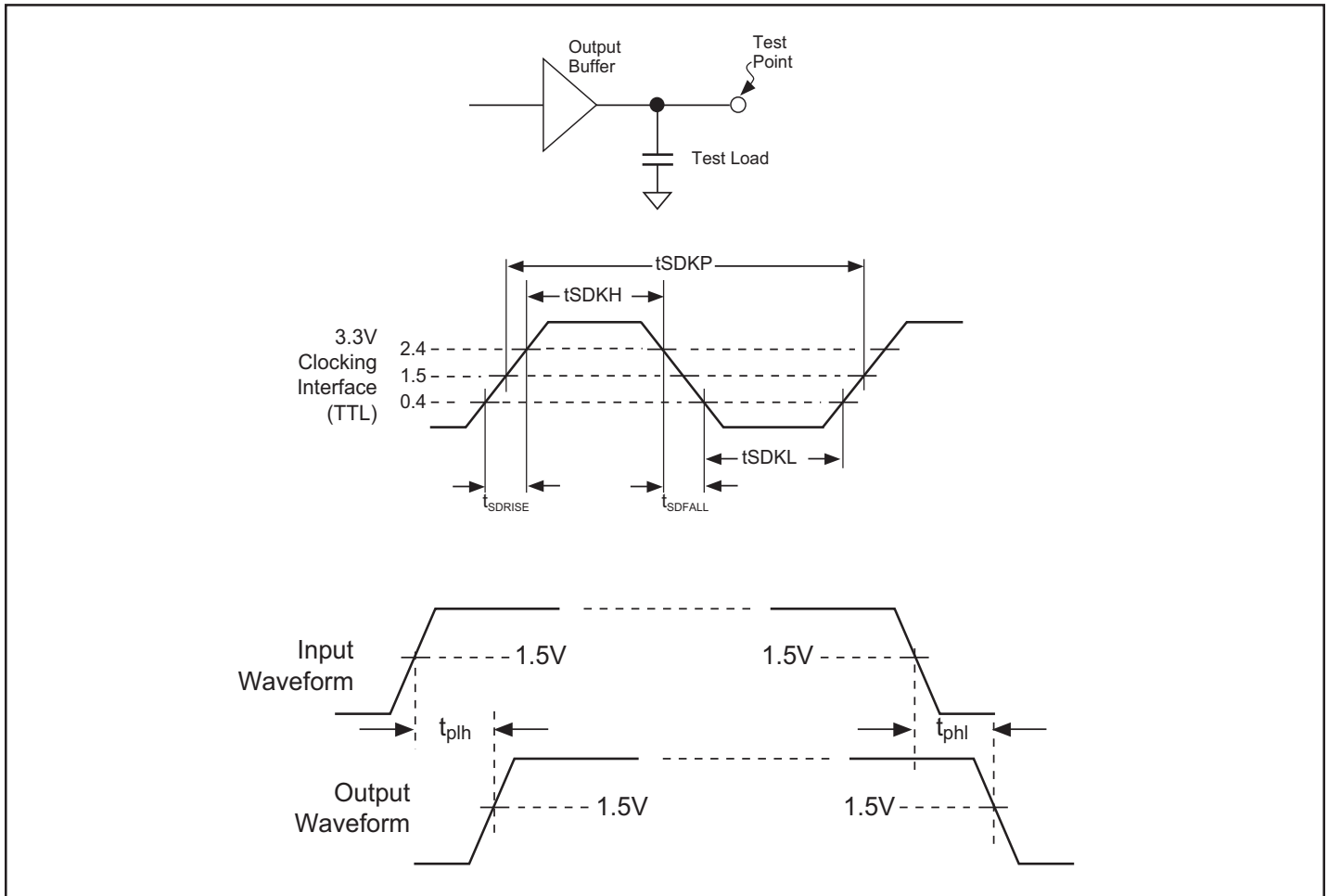


Figure 1. Clock Waveforms

Minimum and Maximum Expected Capacitive Loads

Clock	Min. Load	Max. Load	Units	Notes
SDRAM	20	30	pF	SDRAM DIMM Specification

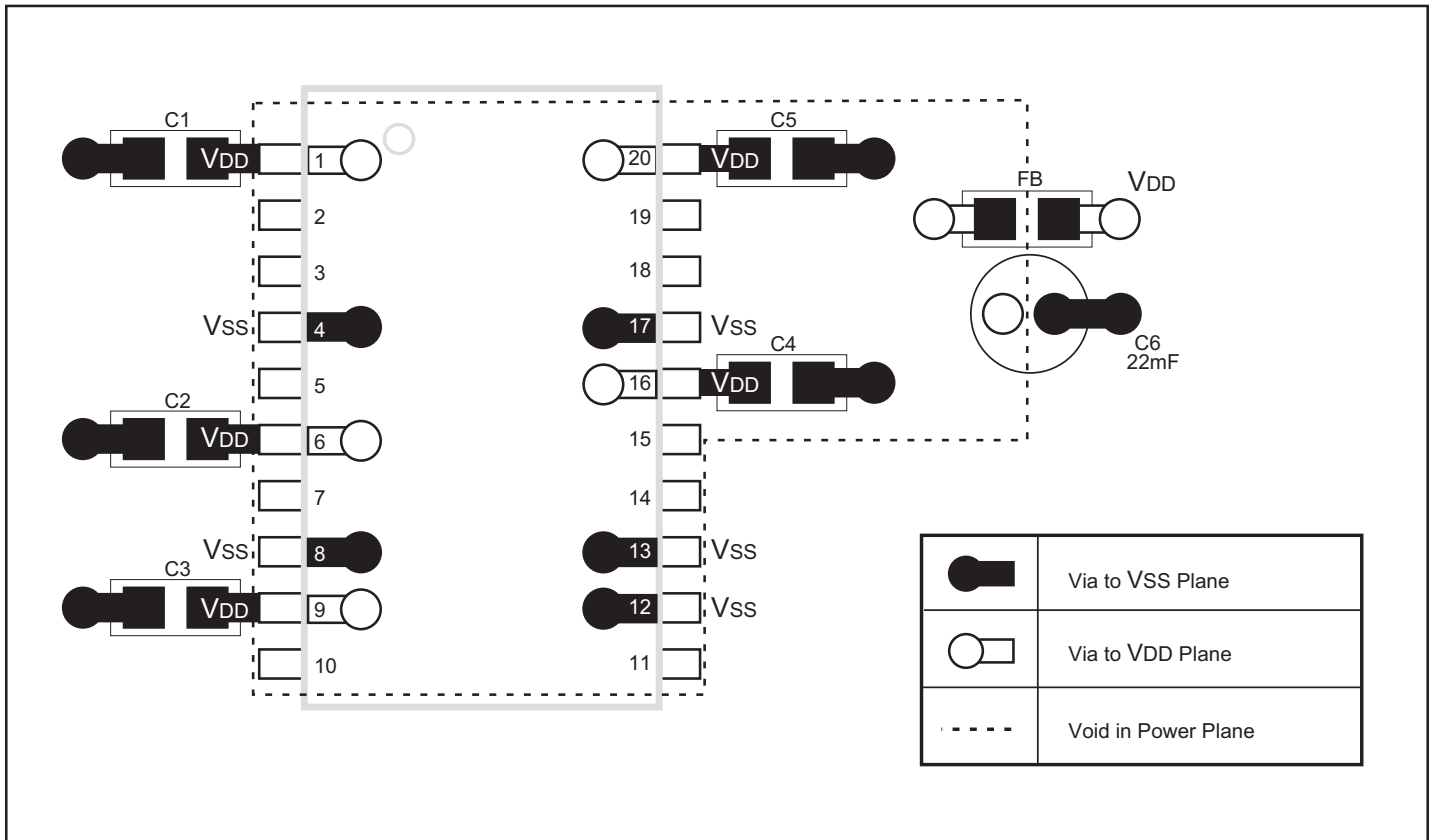
Notes:

1. Maximum rise/fall times are guaranteed at maximum specified load.
2. Minimum rise/fall times are guaranteed at minimum specified load.
3. Rise/fall times are specified with pure capacitive load as shown. Testing is done with an additional 500-ohm resistor in parallel.

Design Guidelines to Reduce EMI

1. Place series R_S resistors and CI capacitors as close as possible to the respective clock pins. Typical value for CI is 10pF. R_S Series resistor value can be increased to reduce EMI provided that the rise and fall time are still within the specified values.
2. Minimize the number of “vias” of the clock traces.
3. Route clock traces over a continuous ground plane or over a continuous power plane. Avoid routing clock traces from plane to plane (refer to rule #2).
4. Position clock signals away from signals that go to any cables or any external connectors.

PCB Layout Suggestion



Note:

This is only a suggested layout. There may be alternate solutions depending on actual PCB design and layout.

As a general rule, C1-C5 should be placed as close as possible to their respective V_{DD}.

Recommended capacitor values:

C1-C5 0.1μF, ceramic

C6 22μF

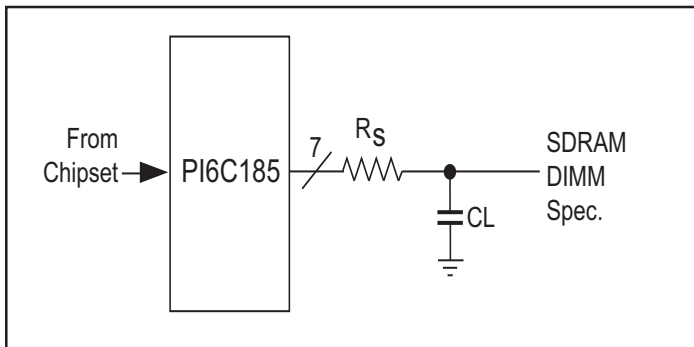
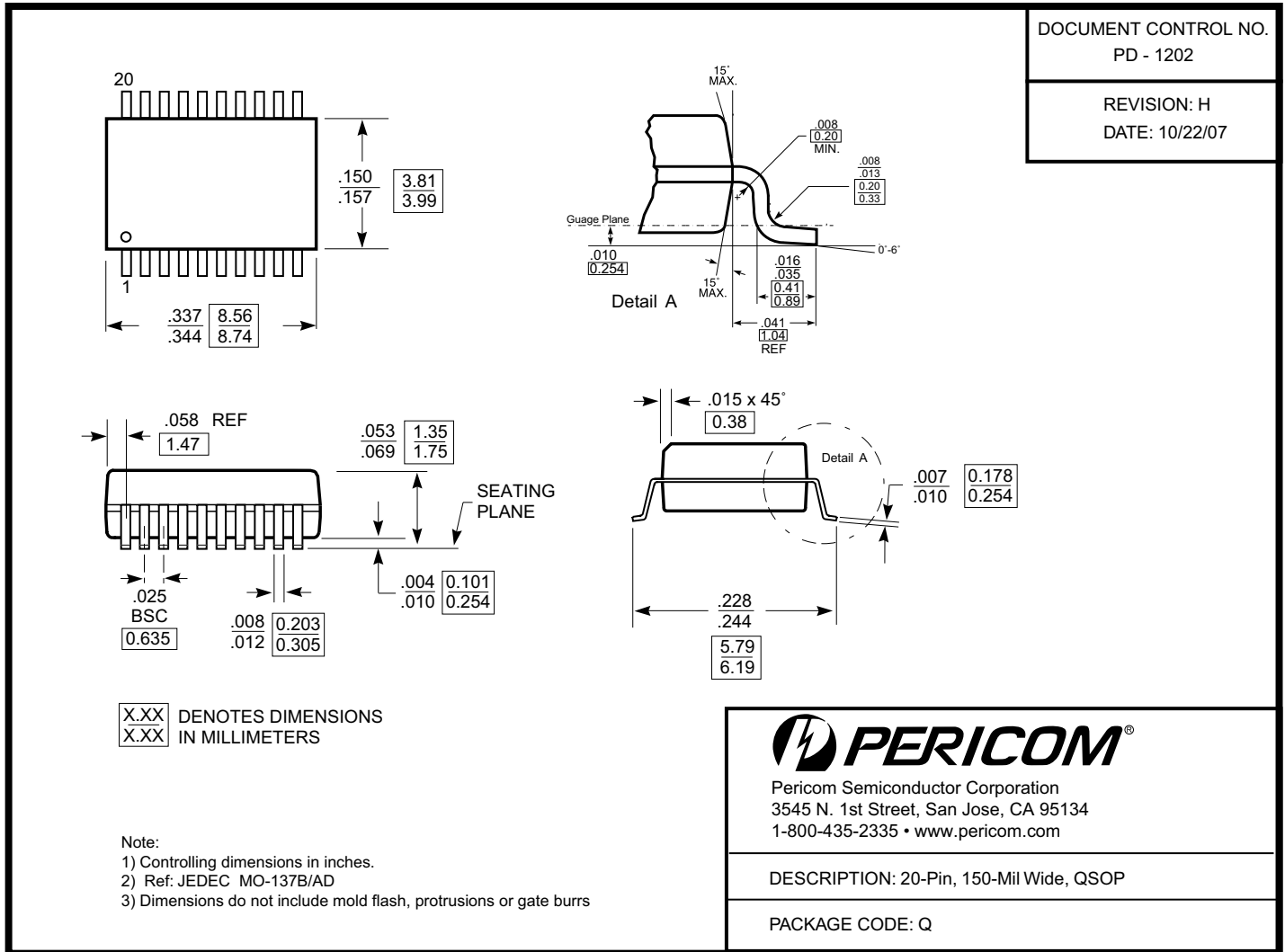


Figure 2. Design Guidelines

Package Mechanical: 20-Pin QSOP (Q)



Ordering Information

Ordering Code	Max.Frequency	Package Description (Code)	Operating Temperature
PI6C185-00QE	125MHz	Pb-free & Green, 20-Pin QSOP (Q)	Commercial
PI6C185-00QIE	125MHz	Pb-free & Green, 20-Pin QSOP (Q)	Industrial

Notes:

- Thermal characteristics can be found on the company web site at www.pericom.com/packaging/
- X = Tape and reel